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High Voltage Surface Mount Input Rectifier Diode, 10 A



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PRIMARY CHARACTERISTICS				
I _{F(AV)}	10 A			
V _R	800 V, 1000 V, 1200 V			
V _F at I _F	1.1 V			
I _{FSM}	160 A			
T _J max.	150 °C			
Package	D ² PAK (TO-263AB)			
Circuit configuration	Single			

FEATURES

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Glass passivated pellet chip junction
- \bullet Designed and qualified according to ${\sf JEDEC}^{\circledast}{\sf -}{\sf JESD}$ 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Input rectification
- Vishay switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-10ETS..S-M3 rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS						
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS						
Capacitive input filter $T_A = 55 \text{ °C}$, $T_J = 125 \text{ °C}$ common heatsink of 1 °C/W	12.0	16.0	А			

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	YMBOL CHARACTERISTICS VALUES					
I _{F(AV)}	Sinusoidal waveform	10	А			
V _{RRM}		800 to 1200	V			
I _{FSM}		160	А			
V _F	10 A, T _J = 25 °C	1.1	V			
TJ		-40 to +150	°C			

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA
VS-10ETS08S-M3	800	900	
VS-10ETS10S-M3	1000	1100	0.5
VS-10ETS12S-M3	1200	1300	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	$T_C = 105$ °C, 180° conduction half sine wave	10			
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, rated V _{RRM} applied	135	A		
	I _{FSM}	10 ms sine pulse, no voltage reapplied	160			
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	91	A ² s		
Maximum Pt for fusing	1-1	10 ms sine pulse, no voltage reapplied	130	A-2		
Maximum I²√t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1290	A²√s		

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST	VALUES	UNITS			
Maximum forward voltage drop	V _{FM}	10 A, T _J = 25 °C		1.1	V		
Forward slope resistance	r _t	T.I = 150 °C	20	mΩ			
Threshold voltage	V _{F(TO)}	1J=150 C	0.82	V			
Maximum ravaraa laakaga aurrant		T _J = 25 °C	V _B = rated V _{BBM}	0.05	m۸		
Maximum reverse leakage current	IRM	T _J = 150 °C	VR = rated VRRM	0.50	mA		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W			
Maximum thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		62	-C/W			
Approximate weight			2	g			
Approximate weight			0.07	oz.			
			10ET	S08S			
Marking device		Case style D ² PAK (TO-263AB)	10ETS10S				
			10ET	S12S			

Note

(1) When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W.

For recommended footprint and soldering techniques refer to application note #AN-994

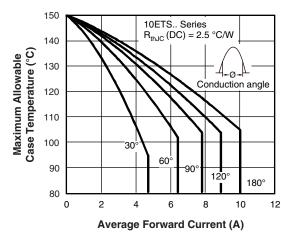


Fig. 1 - Current Rating Characteristics

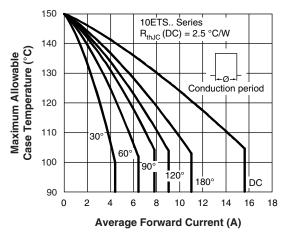
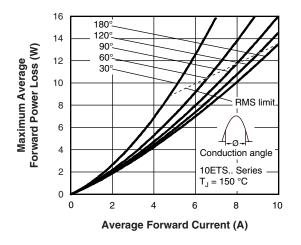


Fig. 2 - Current Rating Characteristics

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Fig. 3 - Forward Power Loss Characteristics

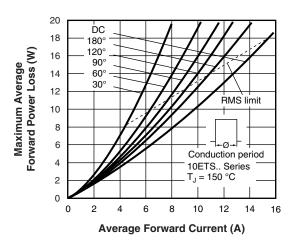
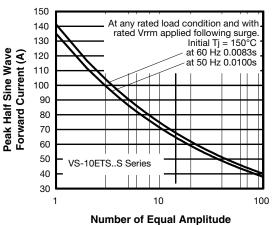


Fig. 4 - Forward Power Loss Characteristics



Half Cycle Current Pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

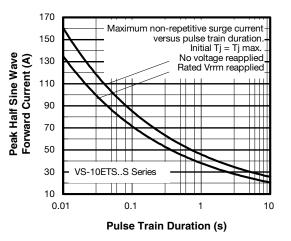


Fig. 6 - Maximum Non-Repetitive Surge Current

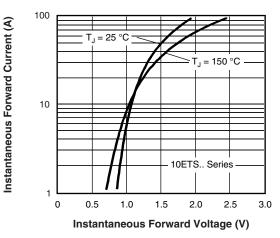
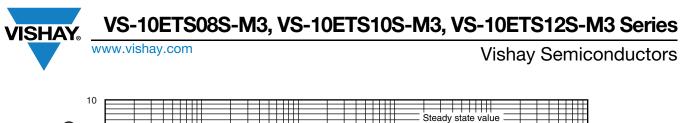


Fig. 7 - Forward Voltage Drop Characteristics



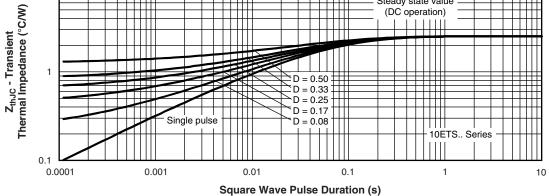


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code	VS-	10	Е	т	S	12	S	TRL	-M3
		(2)	(3)	(4)	(5)	6	(7)	(8)	(9)
	1 ·	· Visl	nay Sen	nicondul	tors prod	duct			
	2 -		-	ng (10 =	-				
	3 -			iguratior	-				
			= single	-					
	4 -		kage:						
			-	K (TO-2	63AB)				
	5 -		e of silio	-					
		S	= stand	ard reco	overy ree	ctifier	Г	08 = 80	0 V 0
	6 -	Volt	age coo	le x 100	= V _{RRM}	1		10 = 10	
	7 -	S =	surface	mounta	able			12 = 12	00 V
	8 -	• N	one = tu	be					
		• TI	RL = tap	e and re	eel (left	oriented	d)		
		• TI	R = tap	be and r	eel (righ	nt orient	ed)		
	9	M	3 = halo	gen-free	e, RoHS	-compli	ant, and	d termin	ations I

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ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-10ETS08S-M3	50	Antistatic plastic tube				
VS-10ETS08STRR-M3	800	13" diameter reel				
VS-10ETS08STRL-M3	800	13" diameter reel				
VS-10ETS10S-M3	50	Antistatic plastic tube				
VS-10ETS10STRR-M3	800	13" diameter reel				
VS-10ETS10STRL-M3	800	13" diameter reel				
VS-10ETS12S-M3	50	Antistatic plastic tube				
VS-10ETS12STRR-M3	800	13" diameter reel				
VS-10ETS12STRL-M3	800	13" diameter reel				
VS-10ETS08S-M3	50	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96164			
Part marking information	www.vishay.com/doc?95444			
Packaging information	www.vishay.com/doc?96424			

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D²PAK

DIMENSIONS in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010 BSC		
L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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